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# N-Channel 100-V (D-S) MOSFET

PRODUCT	SUMMARY				
V <sub>(BR)DSS</sub> (V)	r <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)			
100	0.015 at $V_{GS}$ = 10 V	68 <sup>a</sup>			

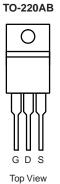
#### **FEATURES**

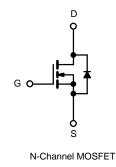
- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- Low Thermal Resistance Package
- 100 % Rg Tested

#### **APPLICATIONS**

• Isolated DC/DC Converters







<b>ABSOLUTE MAXIMUM RATINGS</b> $T_{C} = 25 \text{ °C}$ , unless otherwise noted				
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V <sub>DS</sub>	100	v
Gate-Source Voltage		V <sub>GS</sub>	± 20	v
Continuous Drain Current ( $T_1 = 175 ^{\circ}C$ )	T <sub>C</sub> = 25 °C	1-	68 <sup>a</sup>	
Continuous Drain Current $(T_j = T/5 C)$	T <sub>C</sub> = 125 °C	I <sub>D</sub>	41 <sup>a</sup>	
Pulsed Drain Current		I <sub>DM</sub>	210	A
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	65	
Single Pulse Avalanche Energy <sup>b</sup>		E <sub>AS</sub>	78	mJ
	T <sub>C</sub> = 25 °C	P	395 <sup>c</sup>	10/
Maximum Power Dissipation <sup>b</sup>	T <sub>A</sub> = 25 °C <sup>d</sup>	– P <sub>D</sub> –	3.82	W
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Limit	Unit
Junction-to-Ambient	PCB Mount (TO-263) <sup>d</sup>	R <sub>thJA</sub>	38	°C/W
Junction-to-Case (Drain)		R <sub>thJC</sub>	0.4	0/11

Notes:

- a. Package limited.
- b. Duty cycle  $\leq$  1 %.
- c. See SOA curve for voltage derating.
- d. When Mounted on 1" square PCB (FR-4 material).

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<b>SPECIFICATIONS</b> $T_J = 25^{\circ}$		Test Conditions	Mim	Tree	Mex	lm <sup>14</sup>
Parameter Static	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
	Versee	V <sub>DS</sub> = 0 V, I <sub>D</sub> = 250 μA	100	1		
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	56 5 1	100			V
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		4	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
		$V_{DS} = 80 V$ , $V_{GS} = 0 V$			1	μA
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 \text{ °C}$			50	
		$V_{DS} = 80 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $T_{J} = 175 \text{ °C}$			250	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	68			A
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A		0.015	0.020	
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS}$ = 10 V, $I_{D}$ = 15 A, $T_{J}$ = 125 °C		0.020	0.029	Ω
		$V_{GS}$ = 10 V, $I_{D}$ = 10 A, $T_{J}$ = 175 °C		0.024	0.033	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 80 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		100		S
Dynamic <sup>b</sup>	-					
Input Capacitance	C <sub>iss</sub>			2480		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, f = 1 MHz		230		
Reverse Transfer Capacitance	C <sub>rss</sub>			110		
Total Gate Charge <sup>c</sup>	Qg			90	130	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$		23		nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			34		
Gate Resistance	R <sub>g</sub>		0.5	1.7	3.3	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			24	35	
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 50 \text{ V}, \text{ R}_{I} = 1.5 \Omega$		230	330	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 20$ A, $V_{GEN} = 10$ V, $R_q = 2.5 \Omega$		46	70	ns
Fall Time <sup>c</sup>	t <sub>f</sub>			205	300	-
Source-Drain Diode Ratings and Cha	aracteristics 7	「 <sub>C</sub> = 25 °C <sup>b</sup>				
Continuous Current	I <sub>S</sub>				68	_
Pulsed Current	I <sub>SM</sub>				210	A
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 20 A, V <sub>GS</sub> = 0 V		1.0	1.5	V
Reverse Recovery Time	t <sub>rr</sub>			133	200	ns
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>	I <sub>F</sub> = 20 A, di/dt = 100 A/μs		8	12	A
Reverse Recovery Charge	Q <sub>rr</sub>			0.53	1.2	μC

Notes:

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

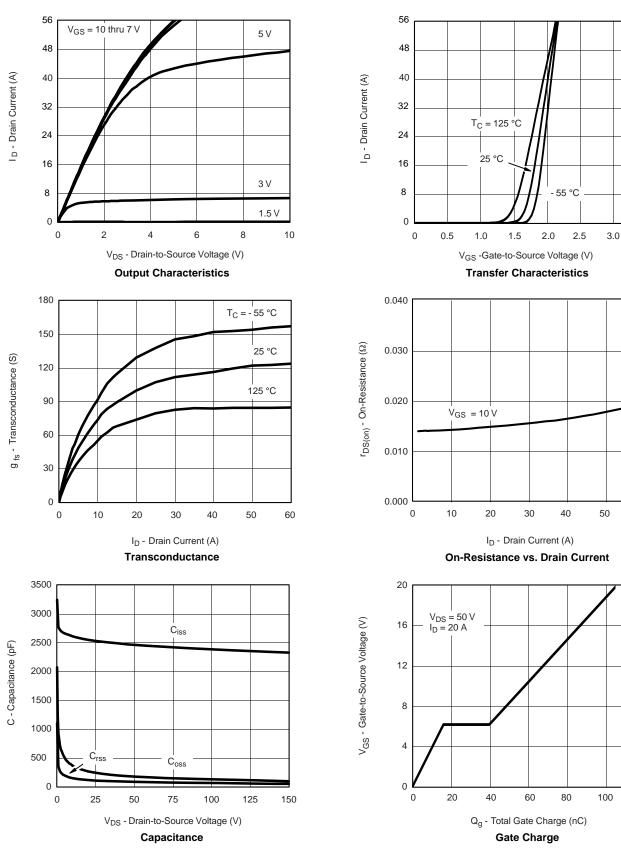


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3.5

60

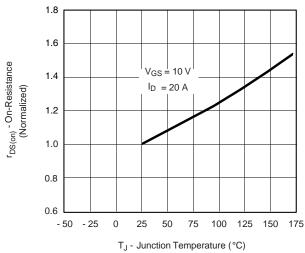




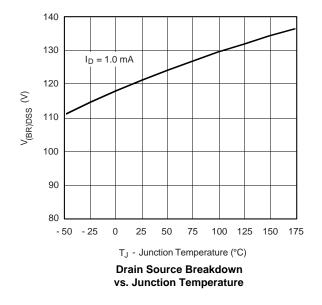
120

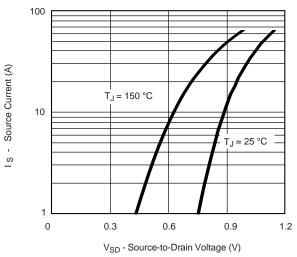
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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

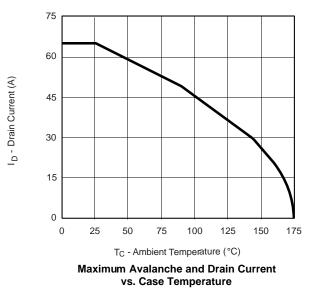








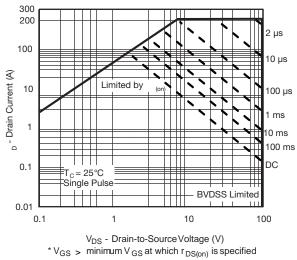
Source-Drain Diode Forward Voltage



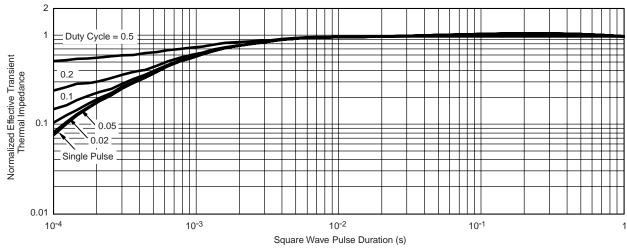


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#### **THERMAL RATINGS**





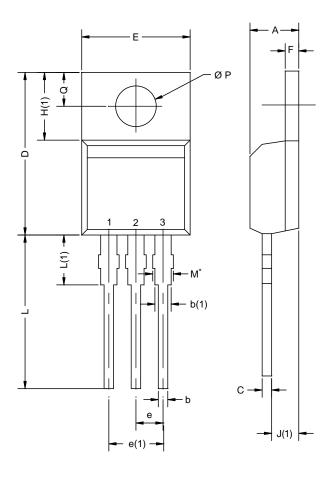


Normalized Thermal Transient Impedance, Junction-to-Case



# Package Information www.din-tek.jp

# **TO-220AB**



	MILLIN	IETERS	INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	16.49	0.585	0.650
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	12.35	14.02	0.486	0.552
L(1)	3.32	3.82	0.131	0.150
ØΡ	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: X12- DWG: 547	0208-Rev. N, 1	08-Oct-12		

#### Notes

\* M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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